



74VHC240 Octal Buffer/Line Driver with 3-STATE Outputs

Features

- High Speed: t_{PD} = 3.6ns (typ) at T_A = 25°C
- Low power dissipation: $I_{CC} = 4\mu A \text{ (max)} @ T_A = 25^{\circ}C$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min.)
- Power down protection is provided on all inputs
- Low noise: V_{OLP} = 0.9V (max.)
- Pin and function compatible with 74HC240

General Description

The VHC240 is an advanced high speed CMOS octal bus buffer fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHC240 is an inverting 3-STATE buffer having two active-LOW output enables. This device is designed to drive buslines or buffer memory address registers.

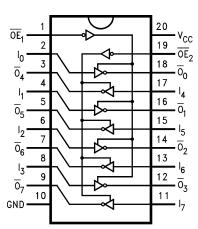
An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Ordering Information

Order Number	Package Number	Package Description
74VHC240M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74VHC240SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC240MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering number. Pb-Free package per JEDEC J-STD-020B.

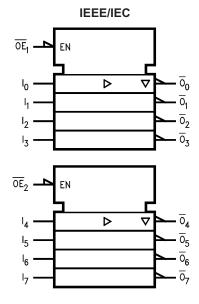
Connection Diagram



Pin Descriptions

Pin Names	Description
\overline{OE}_1 , \overline{OE}_2	3-STATE Output Enable Inputs
I ₀ –I ₇	Inputs
\overline{O}_0 – \overline{O}_7	Outputs 3-STATE Outputs

Logic Symbol



Truth Tables

Inp	uts	Outputs
ŌE ₁	In	(Pins 12, 14, 16, 18)
L	L	Н
L	Н	L
Н	Х	Z

Inp	uts	Outputs
OE ₁	In	(Pins 3, 5, 7, 9)
L	L	Н
L	Н	L
Н	Х	Z

H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

Z = High Impedance

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5V to +7.0V
V _{IN}	DC Input Voltage	-0.5V to +7.0V
V _{OUT}	DC Output Voltage	–0.5V to V _{CC} + 0.5V
I _{IK}	Input Diode Current	–20mA
I _{OK}	Output Diode Current	±20mA
I _{OUT}	DC Output Current	±25mA
I _{CC}	DC V _{CC} /GND Current	±75mA
T _{STG}	Storage Temperature	–65°C to +150°C
T _L	Lead Temperature (Soldering, 10 seconds)	260°C

Recommended Operating Conditions⁽¹⁾

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	2.0V to +5.5V
V _{IN}	Input Voltage	0V to +5.5V
V _{OUT}	Output Voltage	0V to V _{CC}
T _{OPR}	Operating Temperature	–40°C to +85°C
t _r , t _f	Input Rise and Fall Time,	
	$V_{CC} = 3.3V \pm 0.3V$	0ns/V ~ 100ns/V
	$V_{CC} = 5.0V \pm 0.5V$	0ns/V ~ 20ns/V

Note:

1. Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

·							$T_A =$			
			l		25°C			-40°C t	o +85°C	1
Symbol	Parameter	V _{CC} (V) Conditions		Min.	Min. Typ.		Min.	Max.	Units	
V _{IH}	HIGH Level	2.0			1.50			1.50		V
	Input Voltage	3.0–5.5			0.7 x V _{CC}			0.7 x V _{CC}		
V _{IL}	LOW Level Input	2.0					0.50		0.50	V
	Voltage	3.0-5.5					0.3 x V _{CC}		0.3 x V _{CC}	
V _{OH}	HIGH Level	2.0	$V_{IN} = V_{IH}$	$I_{OH} = -50\mu A$	1.9	2.0		1.9		V
	Output Voltage	3.0	or V _{IL}		2.9	3.0		2.9		
voltage	Voltage	4.5			4.4	4.5		4.4		
	3.0		I _{OH} = –4mA	2.58			2.48			
		4.5		$I_{OH} = -8mA$	3.94			3.80		
V _{OL}	LOW Level	2.0		$I_{OL} = 50\mu A$		0.0	0.1		0.1	V
	Output Voltage	3.0	or V _{IL}			0.0	0.1		0.1	
		4.5				0.0	0.1		0.1	
		3.0		I _{OL} = 4mA			0.36		0.44	
		4.5		I _{OL} = 8mA			0.36		0.44	
I _{OZ}	3-STATE Output Off-State Current	5.5	$V_{IN} = V_{IH} \text{ or } V_{IL};$ $V_{OUT} = V_{CC} \text{ or GND}$				±0.25		±2.5	μΑ
I _{IN}	Input Leakage Current	0–5.5	V _{IN} = 5.5V or GND				±0.1		±1.0	μA
I _{CC}	Quiescent Supply Current	5.5	$V_{IN} = V_{CC}$	or GND			4.0		40.0	μA

Noise Characteristics

				T _A = 25°C		
Symbol	Parameter	V _{CC} (V)	Conditions	Тур.	Limits	Units
V _{OLP} ⁽²⁾	Quiet Output Maximum Dynamic V _{OL}	5.0	C _L = 50pF	0.6	0.9	V
V _{OLV} ⁽²⁾	Quiet Output Minimum Dynamic V _{OL}	5.0	C _L = 50pF	-0.6	-0.9	V
V _{IHD} ⁽²⁾	Minimum HIGH Level Dynamic Input Voltage	5.0	C _L = 50pF		3.5	V
V _{ILD} ⁽²⁾	Maximum LOW Level Dynamic Input Voltage	5.0	C _L = 50pF		1.5	V

Note:

2. Parameter guaranteed by design.

AC Electrical Characteristics

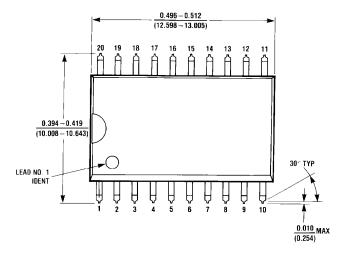
					Т	_A = 25°	С		–40°C 85°C	
Symbol	Parameter	V _{CC} (V)	Cond	litions	Min.	Тур.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}		3.3 ± 0.3		C _L = 15pF		5.3	7.5	1.0	9.0	ns
	Time			$C_L = 50pF$		7.8	11.0	1.0	12.5	
		5.0 ± 0.5		C _L = 15pF		3.6	5.5	1.0	6.5	
				C _L = 50pF		5.1	7.5	1.0	8.5	
t _{PZL} , t _{PZH}	3-STATE Output	3.3 ± 0.3	$R_L = 1k\Omega$	C _L = 15pF		6.6	10.6	1.0	12.5	ns
	Enable Time			$C_L = 50pF$		9.1	14.1	1.0	16.0	
		5.0 ± 0.5		C _L = 15pF		4.7	7.3	1.0	8.5	
				$C_L = 50pF$		6.2	9.3	1.0	10.5	
t _{PLZ} , t _{PHZ}	3-STATE Output	3.3 ± 0.3	$R_L = 1k\Omega$	$C_L = 50pF$		10.3	14.0	1.0	16.0	ns
	Disable Time	5.0 ± 0.5		$C_L = 50pF$	6.7		9.2	1.0	10.5	
t _{OSLH} ,	Output to Output	3.3 ± 0.3	(3)	$C_L = 50pF$			1.5		1.5	ns
toshl	Skew	5.0 ± 0.5		$C_L = 50pF$			1.0		1.0	
C _{IN}	Input Capacitance		V _{CC} = Ope	n		4	10		10	pF
C _{OUT}	Output Capacitance		V _{CC} = 5.0\	/		6				pF
C _{PD}	Power Dissipation Capacitance		(4)			17				pF

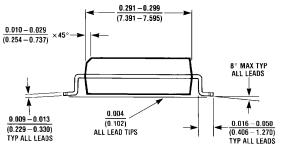
Notes:

- $3. \ \text{Parameter guaranteed by design.} \ t_{\text{OSLH}} = |t_{\text{PLHmax}} t_{\text{PLHmin}}|; \ t_{\text{OSHL}} = |t_{\text{PHLmax}} t_{\text{PHLmin}}|$
- 4. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} V_{CC} f_{IN} + I_{CC} / 8 (per bit).

Physical Dimensions

Dimensions are in inches (millimeters) unless otherwise noted.





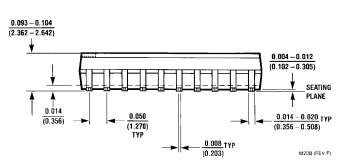
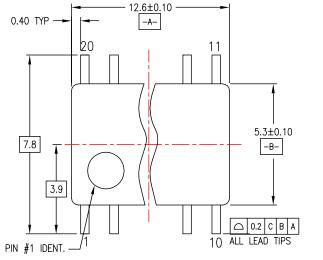
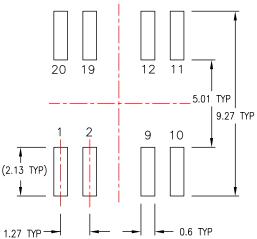


Figure 1. 20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Package Number M20B

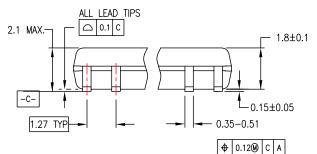
Physical Dimensions (Continued)

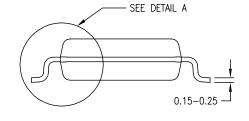
Dimensions are in millimeters unless otherwise noted.





LAND PATTERN RECOMMENDATION





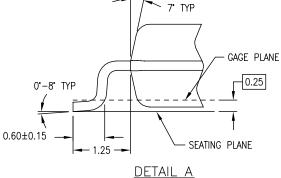
DIMENSIONS ARE IN MILLIMETERS

- NOTES:

 A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

 B. DIMENSIONS ARE IN MILLIMETERS.

 C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

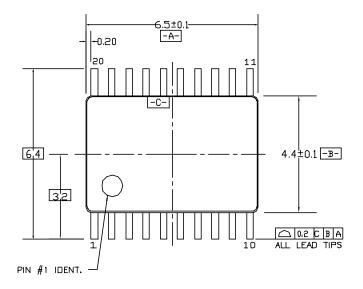


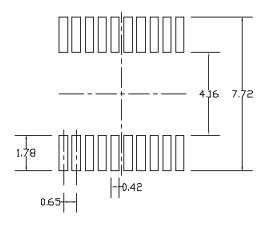
M20DREVC

Figure 2. 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide Package Number M20D

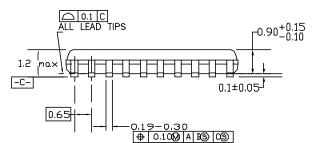
Physical Dimensions (Continued)

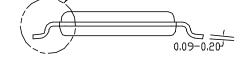
Dimensions are in millimeters unless otherwise noted.





LAND PATTERN RECOMMENDATION





SEE DETAIL A

DIMENSIONS ARE IN MILLIMETERS

-0.6±0.1- R0.09min GAGE PLANE -8°7 -0.6±0.1- R0.09min

DETAIL A

NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MD-153, VARIATION AC, REF NOTE 6, DATE 7/93.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.
- D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20REVD1

Figure 3. 20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC20





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